

CDR on Silicon Tracker

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outlines

- introduction
 - tracking requirements
 - material budget
 - dE/dx ?
 - role in global tracking (with TPC, VTX)
- baseline design
 - detector layout and geometry
 - simulation study and optimisation
 - standalone (fast) simulation?
- technology options
 - silicon microstrip
 - silicon pixel
 - mixture?

outlines

- silicon microstrip sensors
 - sensor $10 \times 10 \text{ cm}^2$, pitch $50 \text{ }\mu\text{m}$, $\sigma_{\text{sp}} < 7 \text{ }\mu\text{m}$, thickness $\sim 200 \text{ }\mu\text{m}$
- silicon pixel sensors
 - CMOS pixel sensors
 - sensors size and layout
 - nearly full processing circuits in pixel/chip: ADC, sparsification, zero-suppression, timing, etc
 - grouped readout electronics scheme
- front-end electronics
 - ASIC
 - optic-links
- powering and cooling
 - a survey of the last developments
 - powering based on DC-DC converters
 - silicon micro-channel cooling

outlines

- mechanics, assembly and alignment
 - support structure and material
 - carbon fibre reinforced polymer (CFRP)
 - module assembly
 - integration and alignment with other sub-detectors (VTX, TPC)
- tracking performance
 - tracking schemes comparison: standalone, with VTX and/or TPC
 - central region and end-cap regions
 - impact parameter resolution in the region of very small solid angle, $\theta < 10^\circ$
 - effect of beam-reduced background
- critical R&D
 - to be identified ...
- cost estimate